

IXTA2N100 Datasheet



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DiGi Electronics Part Number IXTA2N100-DG

Manufacturer IXYS

Manufacturer Product Number IXTA2N100

Description MOSFET N-CH 1000V 2A TO263

Detailed Description N-Channel 1000 V 2A (Tc) 100W (Tc) Surface Mount

TO-263AA



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXTA2N100	IXYS
Series:	Product Status:
	Last Time Buy
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
1000 V	2A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	70hm @ 1A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
4.5V @ 250μA	18 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	825 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	100W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
TO-263AA	TO-263-3, D2PAK (2 Leads + Tab), TO-263AB
Base Product Number:	
IXTA2	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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